

## **NCE Automotive N-Channel Super Trench Power MOSFET**

### **Description**

The NCEAP6055AGU uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{\text{DS(ON)}}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

### **Application**

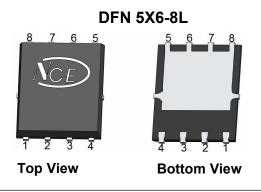
- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

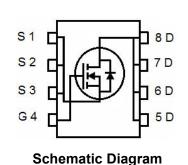
### **General Features**

• V<sub>DS</sub> =60V,I<sub>D</sub> =70A

 $R_{DS(ON)}$ =6.5m $\Omega$  (typical) @  $V_{GS}$ =10V  $R_{DS(ON)}$ =7.7m $\Omega$  (typical) @  $V_{GS}$ =4.5V

- Excellent gate charge X R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 175°C operating temperature
- 100% UIS tested
- 100% ΔVds tested
- Pb-free lead plating
- AEC-Q101 qualified





### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP6055AGU	NCEAP6055AGU	DFN5X6-8L	-	-	-

### Absolute Maximum Ratings (T<sub>c</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	60	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	70	Α
Drain Current-Continuous	I <sub>D</sub> (T <sub>c</sub> =100°C)	55	А
Pulsed Drain Current	I <sub>DM</sub>	280	А
Maximum Power Dissipation	P <sub>D</sub>	78	W
Derating factor		0.52	W/℃
Single pulse avalanche energy (Note 2)	E <sub>AS</sub>	350	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$ C

### **Thermal Characteristic**

Thermal Resistance,Junction-to-Case	Rejc	1.92	°C/W

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## Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

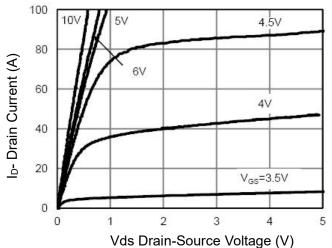
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	60	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.2	1.8	2.4	V
Dunin Sauran On State Besietenen	Б	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	6.5	7.5	
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =20A	-	7.7	8.8	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A		60	-	S
Dynamic Characteristics (Note1)			•			
Input Capacitance	C <sub>iss</sub>	V 20V/V 0V	-	2000	-	pF
Output Capacitance	Coss	$V_{DS}$ =30V, $V_{GS}$ =0V, F=1.0MHz	-	315	-	pF
Reverse Transfer Capacitance	Crss	F-1.UIVITZ	-	9.9	-	pF
Switching Characteristics (Note 1)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	8	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD} = 30V, I_{D} = 20A$	-	2	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =1.6 $\Omega$	-	29	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	4	-	nS
Total Gate Charge	Qg	V 00V L 00A	-	34.8	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =30V,I <sub>D</sub> =20A,	-	7	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	5.3	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-	-	1.2	V
Diode Forward Current	Is		-	-	55	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C, I_F = 20A$	-	38	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	48	-	nC

### Notes:

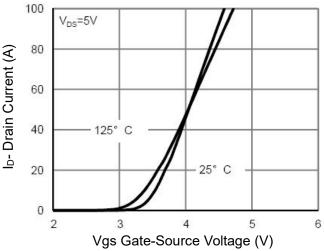
- 1. Defined by design.Not Subject to production test
- 2. EAS condition : Tj=25  $^{\circ}\text{C}$  ,V\_DD=30V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of T<sub>J(MAX)</sub>=175° C. The SOA curve provides a single pulse rating.



### **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

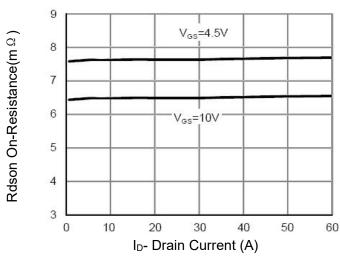


Figure 3 Rdson- Drain Current

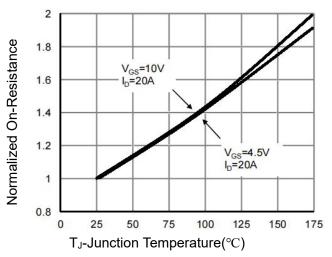


Figure 4 Rdson-Junction Temperature

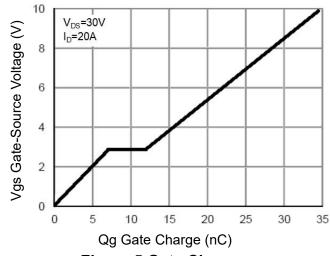


Figure 5 Gate Charge

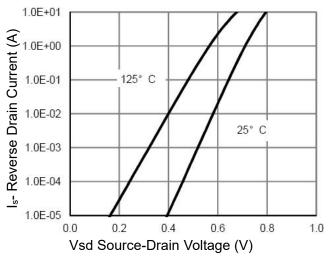


Figure 6 Source- Drain Diode Forward



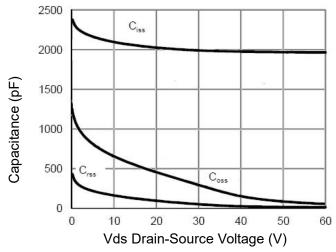


Figure 7 Capacitance vs Vds

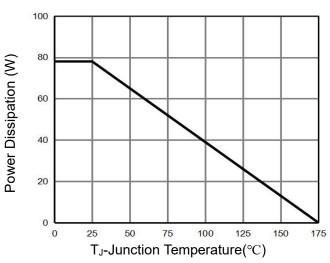


Figure 9 Power De-rating

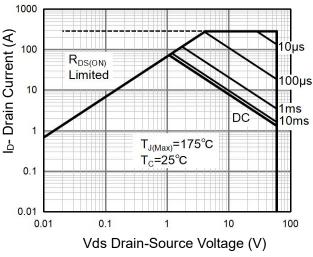


Figure 8 Safe Operation Area(Note 3)

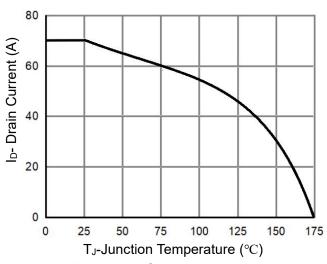


Figure 10 Current De-rating

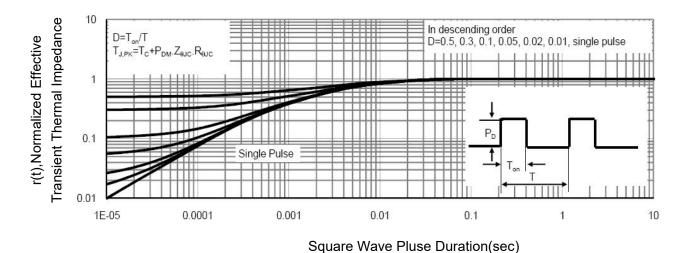
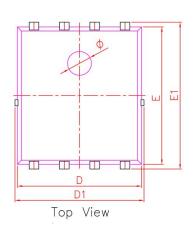
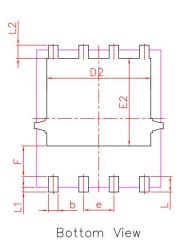


Figure 11 Normalized Maximum Transient Thermal Impedance



## **DFN5X6-8L Package Information**







	PDFN5X6-8L						
DIM.	MIN.	NOM.	MAX.				
Α	0.90	0.95	1.00				
A1	0.00	0.02	0.05				
ь	0.35	0.40	0.50				
С	0.20	0.25	0.30				
D	5.10	5.20	5.30				
D1	5.10	5.40	5.50				
D2	4.25	4.35	4.45				
е	1.27 BSC						
Ε	5.70	5.75	5.80				
E1	6.00	6.15	6.30				
E2	3.57	3.67	3.77				
F	1.18	1.28	1.38				
L	0.55	0.65	0.75				
L1	0.15	0.20	0.25				
L2	0.45	0.55	0.65				
Ø	0.90	1.00	1.10				
Θ	8°	10°	12°				
All dimensions in millimeters							

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